

WASHINGTON, DC 20006

UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	D. FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/976,278	09/976,278 10/15/2001		Genji Imai	011381	1088
23850	7590	03/04/2004		EXAMINER	
ARMSTRO 1725 K STRI		ATZ, QUINTOS,	THORNTON, YVETTE C		
SUITE 1000	,		ART UNIT	PAPER NUMBER	

DATE MAILED: 03/04/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	09/976,278	IMAI, GENJI				
Office Action Summary	Examiner	Art Unit				
	Yvette C. Thornton	1752				
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period of the	36(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) day, will apply and will expire SIX (6) MONTHS from a cause the application to become ARANDONE.	nely filed s will be considered timely. the mailing date of this communication.				
Status						
Responsive to communication(s) filed on 12 D This action is FINAL . 2b)⊠ This Since this application is in condition for allower closed in accordance with the practice under E	action is non-final. nce except for formal matters, pro					
Disposition of Claims						
4) Claim(s) 1 and 5-14 is/are pending in the appliance of the above claim(s) is/are withdraw 5) Claim(s) is/are allowed. 6) Claim(s) 1 and 5-14 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or	vn from consideration.					
Application Papers						
9) The specification is objected to by the Examine						
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.						
Applicant may not request that any objection to the		• •				
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex						
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the prior application from the International Bureau * See the attached detailed Office action for a list of	s have been received. s have been received in Application ity documents have been receive (PCT Rule 17.2(a)).	on No d in this National Stage				
Attachment(s)						
1) Notice of References Cited (PTO-892)	4) Interview Summary (
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) B) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/Mail Dai 5) Notice of Informal Pa 6) Other:					

Art Unit: 1752

DETAILED ACTION

This is written in reference to application number 09/976278 filed on October 15, 2001 and published as US 2002/0068236 A1 on June 6, 2002.

Response to Amendment

- 1. Claims 2-4 have been cancelled. Claims 1 and 5-14 are currently pending.
- 2. The indicated allowability of claims 4-5 and 11 are withdrawn in view of the newly discovered reference(s) to Bantu et al. (US 6072006). Rejections based on the newly cited reference(s) follow.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 1 and 5-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Bantu et al. (US 6,072,006) in view of Urano et al. (US 6033826 A) and Makoto et al. (JP 09-138502 A, machine translation). Bantu teaches a process for preparing an organically soluble partially cross-linked acid labile polymer. The said polymer may be blended with a photoacid generator in a solvent to formulate a chemically amplified resist composition (c. 2, l. 40-47). The general process for generating the said polymer comprises the steps of providing a polymer with one or more monomer units, wherein at least one of the said units contain one or more pendant COOH or OH groups; and reacting this polymer with a

Art Unit: 1752

polyvinyl ether in the presence of an acid catalyst to form links between at least two polymer chains. In the taught invention polyvinyl ether means a compound with two or more vinyl ethers. In a further embodiment, monovinyl ether is added to the above process to form a ketal or acetal protecting groups by functionalizing the monomer units of the COOH or OH pendant groups. A monovinyl ether is defined by the taught invention as a compound with only one vinyl ether (c. 2, l. 48-63). The preferred hydroxyl based reactant polymers are phenolic or hydroxycycloalkyl-based polymer or mixtures thereof. The more preferred phenolic based polymer is polyhydroxystyrene (PHS) and novolak and the more preferred hydroxycycloalkyl-based reactant polymer is polyvinylcyclohexanol (c. 4, l. 1-14). Any suitable polyvinyl ether may be used for the taught crosslinking process. The preferred ether

has the general formula: (c. 4, l. 15-59). Suitable examples include cyclohexanedimethanol divinyl ether and ethylene glycol divinyl ether (c. 4, l. 60-67). See also column 5, lines 1-45. Bantu further provides a process for forming a pattern which comprises the steps of providing the chemically amplified resist composition comprising the said polymer; coating a substrate with the resist composition; soft-baking the resist; imagewise exposing the resist coated substrate to actinic radiation; and forming a resist image by developing the resist coated substrate. Bantu teaches that radiation sources, which can be used, are all sources, which emit radiation in which the photoacid generator is sensitive (c. 12, l. 60-61). It is the examiner's position that the taught polymer meets the limitations of a carboxyl containing and/or hydroxy phenyl containing resin in combination with an ether linkage containing olefinic unsaturated compound.

Application/Control Number: 09/976,278

Art Unit: 1752

5. Bantu teaches all the limitations of the claimed invention except the use of a (USGB38826A) photosensitizer and a photoacid proliferating agent. Urano teaches that conventional additives for resist materials include phenolic compounds, UV absorbers, sensitivity adjusting agents, plasticizers, photosensitizers, organic acids, surfactants etc. (c. 22, l. 33-39).

6. Makoto et al. (JP 09-138502 A, machine translation) teaches that recently in connection with the image recording technology using visible light, the need for a compound, which can be photopolymerized by light, is increasing (p. 0002). Makoto teaches a series of benzopyran ring condensation compound guided from a 3-benzimidazolyl-2-imino coumarin compounds which show photosensitization ability to light with a wavelength of 500 nm or more (p. 0008). Specific compounds include formulae 5-6, 8-10 and 15 (p. 0016-0026).

Formula 5 having the structure:

(5) meets the limitations of

claimed formula (1) when Y=NH, R1=H and R2=H. Formula 6 having the structure:

(6) meets the limitations of claimed formula (1) when Y=0, R1=H

and R2=H. Formula 8 having the structure:

(8) meets the

limitations of claimed formula (1) when Y=NH, R1=H and R2=CN. Formula 9 having the

Application/Control Number: 09/976,278

Art Unit: 1752

structure:

Page 5

V O DI II IDO CNI E I IOI I II

Y=O, R1=H and R2=CN. Formula 10 having the structure:

(10) meets the limitations of claimed formula (1) when Y=NH,

R1=H and R2=CF3. Formula 15 having the structure:

meets the limitations of claimed formula (1) when Y=NH, R1=CF3 and R2=H.

- 7. One of ordinary skill in the art would have been motivated by what is well known and conventional as taught by Urano to incorporate a photosensitizer and an organic acid into the taught composition of Bantu. One of ordinary skill in the art would have been motivated by the teachings of Makoto, and the general trend in the art, to incorporate any one of the taught benzopyran ring condensed compounds of formulae 5-6, 8-10 and 15 into the composition of Bantu, as a photosensitizer, in order to make the composition suitable for exposure to visible light greater than 500 nm.
- 8. Claim 14 is rejected under 35 U.S.C. 103(a) as being unpatentable over Bantu et al. (US 6,072,006) in view of Urano et al. (US 6033826) and Makoto et al. (JP 09-138502 A, machine translation) as applied to claims 1 and 5-13 above, and further in view of Imai et al.

Application/Control Number: 09/976,278

Art Unit: 1752

Page 6

(US 5496678 A). Bantu in view of Urano and Makoto teach all the limitations of the claimed invention except it fails to teach peeling off the support film to form a resist pattern.

9. Imai teaches a photochemical composition, which can be used as a dry film type resist or a transfer film type. In the dry film type resist, the taught composition is coated on a transparent and flexible supporting film. The coated solution is heated to remove the solvent thereby forming a dry film. As necessary, a protective layer maybe formed on the resist side of the said film. Alternatively, it is possible that a resist film is formed on a releasable film and then a supporting film be mounted on the resist film. The adhesivity between the supporting film and the resist film is generally 1/10 or less of the adhesivity between the supporting film and the resist film. The transfer film is prepared in the same manner as the dry film resist except that the adhesivity between the supporting film and the resist film is desirably about 1/3 or less of the adhesivity between the substrate and the resist film when it has been laminated on a substrate. In the case of the transfer film type, the supporting film is peeled off before irradiation. In the case of the dry film type resist, the supporting film is peeled off from the resist film after irradiation (c. 11, l. 7-c. 12, l. 3). It would have been obvious to one of ordinary skill in the art, in light of the teachings of Imai to use the composition Bantu to make a transfer film wherein the supporting film is peeled off prior to irradiation or a dry film type resist wherein the supporting film is peel-off after irradiation.

Response to Arguments

10. Applicant's arguments, filed December 12, 2003, have been fully considered and are persuasive. The rejections set forth in the previous office action are hereby withdrawn.

Art Unit: 1752

Conclusion

11. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Yvette C. Thornton whose telephone number is 571-272-

1336. The examiner can normally be reached on Monday-Thursday from 8:00 am to 6:30

pm.

12. If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Mark F. Huff, can be reached on 571-272-1385. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

13. Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published

applications may be obtained from either Private PAIR or Public PAIR. Status information

for unpublished applications is available through Private PAIR only. For more information

about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access

to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197

(toll-free).

vette Clarke Thornton

Patent Examiner

Art Unit 1752

yct

February 24, 2004